## NSN 5961-01-264-4409

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-264-4409 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-71 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 drain to gate voltage all transistor and 50.0 drain to source voltage all transistor and 50.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes forward current, total rms megawatts all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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